



APT34N80B2C3G Information



For Reference Only

Part Number APT34N80B2C3G
Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 800V 34A T-MAX

Package TO-247-3 Variant

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









APT34N80B2C3G Specifications

Manufacturer Part Number	APT34N80B2C3G
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3 Variant
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	800V
Current - Continuous Drain (Id) @ 25°C	34A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	3.9V @ 2mA
Gate Charge (Qg) (Max) @ Vgs	355nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4510pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	417W (Tc)
Rds On (Max) @ Id, Vgs	145 mOhm @ 22A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	T-MAX? [B2]
Package / Case	TO-247-3 Variant
	Report errors?

APT34N80B2C3G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

APT34N80B2C3G Payment Methods



















APT34N80B2C3G Shipping Methods













If you have any question about APT34N80B2C3G, please do not hesitate to contact us!

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